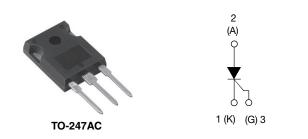
Vishay Semiconductors

High Voltage Phase Control Thyristor, 40 A



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PRODUCT SUMMARY								
Package	TO-247AC							
Diode variation	Single SCR							
I _{T(AV)}	35 A							
V _{DRM} /V _{RRM}	1600 V							
V _{TM}	1.45 V							
I _{GT}	150 mA							
TJ	- 40 °C to 125 °C							

FEATURES

- High voltage (up to 1600 V)
- Designed and qualified according to JEDEC-JESD47
- Compliant to RoHS Directive 2002/95/EC
- 125 °C max. operating junction temperature



• Halogen-free according to IEC 61249-2-21 definition (-M3 only)

APPLICATIONS

• Typical usage is in input rectification crowbar (soft start) and AC switch in motor control, UPS, welding and battery charge

DESCRIPTION

The VS-40TPS16... high voltage series of silicon controlled rectifiers are specifically designed for medium power switching and phase control applications. The glass passivation technology used has reliable operation up to 125 °C junction temperature.

MAJOR RATINGS	MAJOR RATINGS AND CHARACTERISTICS										
PARAMETER	TEST CONDITIONS	VALUES	UNITS								
I _{T(AV)}	Sinusoidal waveform	35	A								
I _{RMS}		55	A								
V _{RRM} /V _{DRM}		1600	V								
I _{TSM}		500	А								
V _T	40 A, T _J = 25 °C	1.45	V								
dV/dt		1000	V/µs								
dl/dt		100	A/µs								
TJ		- 40 to 125	°C								

VOLTAGE RATINGS								
PART NUMBER	V _{RRM} /V _{DRM} , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} /I _{DRM} AT 125 °C mA					
VS-40TPS16PbF, VS-40TPS16-M3	1600	1700	10					



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ABSOLUTE MAXIMUM RATINGS	S					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS	
Maximum average on-state current	I _{T(AV)}	$T_{\rm C}$ = 79 °C, 180° conduction half sine v	wave	35		
Maximum continuous RMS on-state current as AC switch	I _{T(RMS)}			55	A	
Maximum peak, one-cycle	L	10 ms sine pulse, rated V_{RRM} applied		500		
non-repetitive surge current	I _{TSM}	10 ms sine pulse, no voltage reapplied	10 ms sine pulse, no voltage reapplied			
Maximum 12t for fusing	l ² t	10 ms sine pulse, rated V_{RRM} applied	Initial T _J = T _{.1} maximum	1250	A ² s	
Maximum I ² t for fusing	l ² t	10 ms sine pulse, no voltage reapplied	0			
Maximum I²√t for fusing	l²√t	t = 0.1 to 10 ms, no voltage reapplied	12 500	A²√s		
Low level value of threshold voltage	V _{T(TO)1}		1.02	V		
High level value of threshold voltage	V _{T(TO)2}		1.23	v		
Low level value of on-state slope resistance	r _{t1}	T _J = 125 °C		9.74		
High level value of on-state slope resistance	r _{t2}			7.50	mΩ	
Maximum peak on-state voltage	V _{TM}	110 A, T _J = 25 °C		1.85	V	
Maximum rate of rise of turned-on current	dl/dt	T _J = 25 °C		100	A/µs	
Maximum holding current	Ι _Η		150			
Maximum latching current	١L		300			
	1 /1	$T_J = 25 °C$,	0.5	mA	
Maximum reverse and direct leakage current	I _{RRM} /I _{DRM}	$T_J = 125 \text{ °C}$ $V_R = \text{Rated } V_{RRM}/V_R$	/DRM	10		
Maximum rate of rise of off-state voltage	dV/dt	$T_{\rm J}=T_{\rm J}$ maximum, linear to 80 % $V_{\rm DRM}$	1000	V/µs		

TRIGGERING						
PARAMETER	SYMBOL	TE	TEST CONDITIONS			
Maximum peak gate power	P _{GM}			10	W	
Maximum average gate power	P _{G(AV)}					
Maximum peak gate current	I _{GM}			2.5	А	
Maximum peak negative gate voltage	- V _{GM}			10		
		T _J = - 40 °C		4.0	v	
Maximum required DC gate voltage to trigger	V _{GT}	T _J = 25 °C	Anode supply = 6 V resistive load	2.5		
		T _J = 125 °C		1.7		
		T _J = - 40 °C		270		
Maximum required DC acts autrent to trianer		T _J = 25 °C		150	mA	
Maximum required DC gate current to trigger	I _{GT}	T _J = 125 °C		80		
		$T_{\rm J} = 25 \ ^{\circ}{\rm C}$, for 40	40			
Maximum DC gate voltage not to trigger	V _{GD}	T 105 %C V	0.25	V		
Maximum DC gate current not to trigger	I _{GD}	$1J = 125 C, V_{DRM}$	$T_J = 125 \text{ °C}, V_{DRM} = Rated value}$			

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THERMAL AND MECHANICAL SPECIFICATIONS									
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum junction and storage temperature range		T _J , T _{Stg}		- 40 to 125	°C				
Maximum thermal resistance, junction to case		R _{thJC}	R _{thJC} DC operation						
Maximum thermal resistance, junction to ambient		R _{thJA}		40	°C/W				
Maximum thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.2					
Approvimate weight				6	g				
Approximate weight				0.21	oz.				
Mounting torque	minimum			6 (5)	kgf ⋅ cm				
Mounting torque -	maximum			12 (10)	(lbf ⋅ in)				
Marking device			Case style TO-247AC	40TF	PS16				

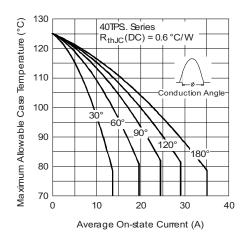


Fig. 1 - Current Rating Characteristics

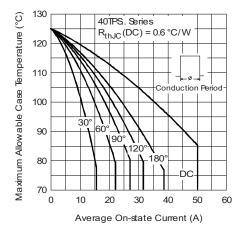


Fig. 2 - Current Rating Characteristics

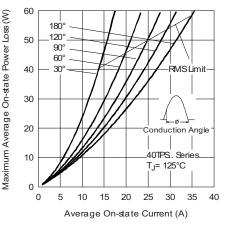


Fig. 3 - On-State Power Loss Characteristics

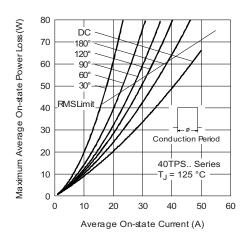


Fig. 4 - On-State Power Loss Characteristics

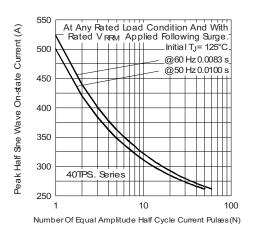
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Fig. 5 - Maximum Non-Repetitive Surge Current

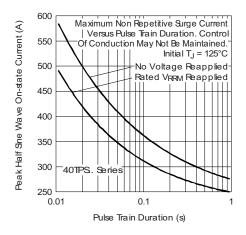


Fig. 6 - Maximum Non-Repetitive Surge Current

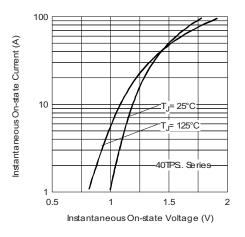


Fig. 7 - On-State Voltage Drop Characteristics

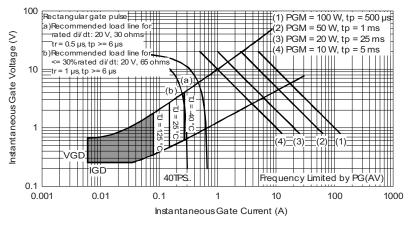


Fig. 8 - Gate Characteristics



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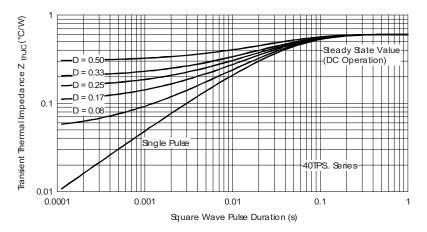


Fig. 9 - Thermal Impedance ZthJC Characteristics

ORDERING INFORMATION TABLE

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Device code	VS-	40	т	Ρ	S	16	PbF
		(2)	(3)	4	(5)	(6)	(7)
	_	\bigcirc	\bigcirc	\bigcirc	Ŭ	\bigcirc	\bigcirc
	1 -		-	niconduc	•	duct	
	2 - 3 -			ng (40 = iguratior	,		
			Thyristo	•			
	4 -	Pac	kage:				
		P =	TO-247				
	5 -		e of silio				
				d recov	-		
	6 -			ng (16 =)	
	7 -			tal digit:			
				(Pb)-fre			-
		-M3	= Halog	en-free,	RoHS	complia	nt, and

ORDERING INFORMATION (Example)								
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION					
VS-40TPS16PbF	25	500	Antistatic plastic tubes					
VS-40TPS16-M3	25	500	Antistatic plastic tubes					

LINKS TO RELATED DOCUMENTS							
Dimensions www.vishay.com/doc?95223							
Part marking information	TO-247AC PbF	www.vishay.com/doc?95226					
	TO-247AC -M3	www.vishay.com/doc?95007					

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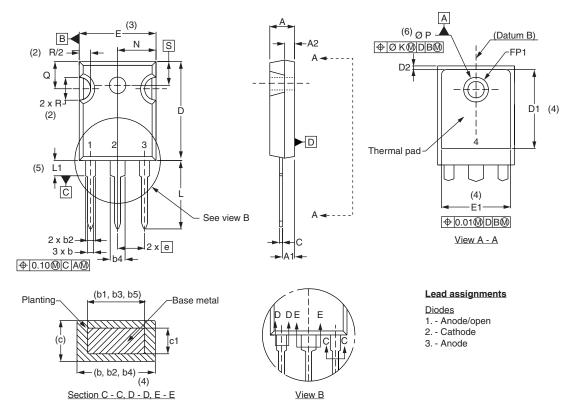
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Outline Dimensions





DIMENSIONS in millimeters and inches



SYMBOL	MILLIMETERS		INC	HES	NOTES	SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STNIBOL	MIN.	MAX.	MIN.	MAX.	NOTES	STWBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.65	5.31	0.183	0.209		D2	0.51	1.30	0.020	0.051	
A1	2.21	2.59	0.087	0.102		E	15.29	15.87	0.602	0.625	3
A2	1.50	2.49	0.059	0.098		E1	13.72	-	0.540	-	
b	0.99	1.40	0.039	0.055		e	5.46	BSC	0.215	BSC	
b1	0.99	1.35	0.039	0.053		FK	2.	54	0.0)10	
b2	1.65	2.39	0.065	0.094		L	14.20	16.10	0.559	0.634	
b3	1.65	2.37	0.065	0.094		L1	3.71	4.29	0.146	0.169	
b4	2.59	3.43	0.102	0.135		Ν	7.62	BSC	0	.3	
b5	2.59	3.38	0.102	0.133		ΦP	3.56	3.66	0.14	0.144	
с	0.38	0.86	0.015	0.034		Φ P1	-	6.98	-	0.275	
c1	0.38	0.76	0.015	0.030		Q	5.31	5.69	0.209	0.224	
D	19.71	20.70	0.776	0.815	3	R	4.52	5.49	1.78	0.216	
D1	13.08	_	0.515	-	4	S	5.51	BSC	0.217	BSC	

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5M-1994

(2) Contour of slot optional

(3) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

⁽⁴⁾ Thermal pad contour optional with dimensions D1 and E1

⁽⁵⁾ Lead finish uncontrolled in L1

(6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")

⁽⁷⁾ Outline conforms to JEDEC outline TO-247 with exception of dimension c

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